ISO7220A, ISO7220B, ISO7220C, ISO7220M ISO7221A, ISO7221B, ISO7221C, ISO7221M

SLLS755H-JULY 2006-REVISED MAY 2008

#### **DUAL DIGITAL ISOLATORS**

#### **FEATURES**

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- 1, 5, 25, and 150-Mbps Signaling Rate Options
  - Low Channel-to-Channel Output Skew; 1 ns max
  - Low Pulse-Width Distortion (PWD); 1 ns max
  - Low Jitter Content; 1 ns Typ at 150 Mbps
- Typical 25-Year Life at Rated Voltage (see app. note SLLA197 and Figure 20)
- 4000-V<sub>peak</sub> Isolation, 560 V peak V<sub>IORM</sub>
  - UL 1577, IEC 60747-5-2 (VDE 0884, Rev 2). IEC 61010-1
  - 50 kV/µs Typical Transient Immunity
- Operates with 3.3-V or 5-V Supplies

- 4 kV ESD Protection
- **High Electromagnetic Immunity**
- -40°C to 125°C Operating Range APPLICATIONS
- **Industrial Fieldbus** 
  - **Modbus**
  - Profibus™
  - DeviceNet™ Data Buses
- **Computer Peripheral Interface**
- Servo Control Interface
- **Data Acquisition**

#### **DESCRIPTION**

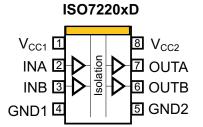
The ISO7220 and ISO7221 are dual-channel digital isolators. To facilitate PCB layout, the channels are oriented in the same direction in the ISO7220 and in opposite directions in the ISO7221. These devices have a logic input and output buffer separated by TI's silicon-dioxide (SiO<sub>2</sub>) isolation barrier, providing galvanic isolation of up to 4000 V. Used in conjunction with isolated power supplies, these devices block high voltage, isolate grounds, and prevent noise currents on a data bus or other circuits from entering the local ground and interfering with or damaging sensitive circuitry.

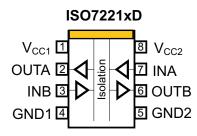
A binary input signal is conditioned, translated to a balanced signal, then differentiated by the capacitive isolation barrier. Across the isolation barrier, a differential comparator receives the logic transition information, then sets or resets a flip-flop and the output circuit accordingly. A periodic update pulse is sent across the barrier to ensure the proper dc level of the output. If this dc-refresh pulse is not received every 4 µs, the input is assumed to be unpowered or not being actively driven, and the failsafe circuit drives the output to a logic high state.

The small capacitance and resulting time constant provide fast operation with signaling rates available from 0 Mbps (dc) to 150 Mbps. (1) The A-, B- and C-option devices have TTL input thresholds and a noise filter at the input that prevents transient pulses from being passed to the output of the device. The M-option devices have CMOS V<sub>CC</sub>/2 input thresholds and do not have the input noise-filter and the additional propagation delay.

These devices require two supply voltages of 3.3 V, 5 V, or any combination. All inputs are 5-V tolerant when supplied from a 3.3-V supply and all outputs are 4-mA CMOS.

These devices are characterized for operation over the ambient temperature range of -40°C to 125°C.





(1) The signaling rate of a line is the number of voltage transitions that are made per second expressed in the units bps (bits per second).

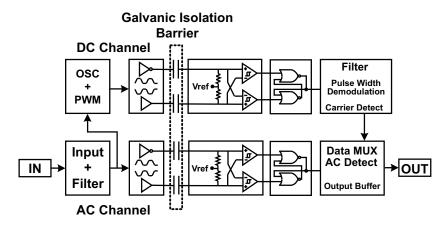
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These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

#### SINGLE-CHANNEL FUNCTION DIAGRAM



#### **AVAILABLE OPTIONS**

PRODUCT	SIGNALING RATE	PACKAGE	INPUT THRESHOLD	CHANNEL DIRECTION	MARKED AS	ORDERING NUMBER		
ISO7220A	1 Mbps	SOIC-8	≈ 1.5 V (TTL)		17220A	ISO7220AD (rail)		
1307220A	1 IVIDPS	3010-6	(CMOS compatible)		17220A	ISO7220ADR (reel)		
ISO7220B	5 Mbps	SOIC-8	≈ 1.5 V (TTL)		17220B	ISO7220BD (rail)		
13072206	5 IVIDPS	3010-6	(CMOS compatible	Same direction	172206	ISO7220BDR (reel)		
ISO7220C	25 Mbps	SOIC-8	≈ 1.5 V (TTL)	Same direction	17220C	ISO7220CD (rail)		
13072200	25 Mbps	SUIU-8	3010-0	3010-0	(CMOS compatible)		17220C	ISO7220CDR (reel)
ISO7220M	4FO Mhno	SOIC-8	\/ /2 (CMOS)		17220M	ISO7220MD (rail)		
1507220W	150 Mbps	SOIC-8	V <sub>CC</sub> /2 (CMOS)		17220101	ISO7220MDR (reel)		
ISO7221A	1 Mbps	SOIC-8	≈ 1.5 V (TTL)		17221A	ISO7221AD (rail)		
1307221A	1 IVIDPS	3010-6	(CMOS compatible)		1722 IA	ISO7221ADR (reel)		
ISO7221B	5 Mbps	SOIC-8	≈ 1.5 V (TTL)		17221B	ISO7221BD (rail)		
13072216	5 IVIDPS	3010-6	(CMOS compatible)	Opposite directions	1/2216	ISO7221ABR (reel)		
ISO7221C	25 Mbpc	SOIC-8	≈ 1.5 V (TTL)	Opposite directions	TI7221C	ISO7221CD (rail)		
130/2210	25 Mbps	3010-8	(CMOS compatible)		11/2210	ISO7221CDR (reel)		
ISO7221M	150 Mbps	SOIC-8	V /2 (CMOS)		17221M	ISO7221MD (rail)		
1307221101	130 Minhs	3010-0	V <sub>CC</sub> /2 (CMOS)		11 22 1 1 1 1	ISO7221MDR (reel)		

#### **REGULATORY INFORMATION**

VDE	CSA	UL
Certified according to IEC 60747-5-2		Recognized under 1577 Component Recognition Program <sup>(1)</sup>
File Number: 40016131	File Number: 1698195	File Number: E181974

(1) Production tested ≥3000 VRMS for 1 second in accordance with UL 1577.



#### ABSOLUTE MAXIMUM RATINGS(1)

					VALUE	UNIT
$V_{CC}$	Supply voltage	( <sup>2)</sup> , V <sub>CC1</sub> , V <sub>CC2</sub>			-0.5 to 6	V
VI	Voltage at IN,	OUT			-0.5 to 6	V
lo	Output current	Dutput current				mA
		Human Body Model	Electrostatic discharge JEDEC Standard 22, Test Method A114-C.01		±4	137
ESD	Electrostatic discharge	Field-Induced-Charged Device Model	JEDEC Standard 22, Test Method C101	All pins	±1	kV
		Machine Model	ANSI/ESDS5.2-1996		±200	V
TJ	Maximum junc		170	°C		

<sup>(1)</sup> Stresses beyond those listed under absolute maximum ratings may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other conditions beyond those indicated under recommended operating conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

#### RECOMMENDED OPERATING CONDITIONS

			MIN	TYP	MAX	UNIT
V <sub>CC</sub>	Supply voltage <sup>(1)</sup> , V <sub>CC1</sub> , V <sub>CC2</sub>		3		5.5	V
I <sub>OH</sub>	High-level output current				4	mA
I <sub>OL</sub>	Low-level output current		-4			mA
		ISO722xA	1	0.67		μs
	Input pulse width	ISO722xB	200	100		
t <sub>ui</sub>	Input pulse width	ISO722xC	40	33		
		ISO722xM	6.67	5	1000 5 25 150 V <sub>CC</sub> 0.8 V <sub>CC</sub>	ns
		ISO722xA	0	1500	1000	kbps
4 /4	Signaling rate	ISO722xB	0	10	5	Mbps
1/t <sub>ui</sub>	Signaling rate	ISO722xC	0	30	25	Mhaa
		ISO722xM	0	200 <sup>(2)</sup>	150	Mbps
V <sub>IH</sub>	High-level input voltage	1007204 1007200	2		V <sub>CC</sub>	V
V <sub>IL</sub>	Low-level input voltage	ISO722xA, ISO722xC	0		0.8	V
V <sub>IH</sub>	High-level input voltage	100700.44	0.7 V <sub>CC</sub>		$V_{CC}$	V
V <sub>IL</sub>	Low-level input voltage	ISO722xM	0		0.3 V <sub>CC</sub>	V
TJ	Junction temperature		-40		150	°C
Н	External magnetic field-strength immunity per I certification	EC 61000-4-8 & IEC 61000-4-9			1000	A/m

For the 5-V operation, V<sub>CC1</sub> or V<sub>CC2</sub> is specified from 4.5 V to 5.5 V. For the 3-V operation, V<sub>CC1</sub> or V<sub>CC2</sub> is specified from 3 V to 3.6 V. Typical sigalling rate under ideal conditions at 25°C.

All voltage values except differential I/O bus voltages are with respect to network ground terminal and are peak voltage values.



# ELECTRICAL CHARACTERISTICS: $V_{\text{CC1}}$ and $V_{\text{CC2}}$ at 5-V<sup>(1)</sup> OPERATION

over recommended operating conditions (unless otherwise noted)

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPL	Y CURRENT						
	ISO7220x	Outenant	\\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\		1	2	
	ISO7221	Quiescent	$V_I = V_{CC}$ or 0 V, no load		8.5	17	
	ISO7220A, ISO7220B	1 Mbps	V - V or 0 V no load		2	3	
I <sub>CC1</sub>	ISO7221A, ISO7221B	1 IVIDPS	$V_I = V_{CC}$ or 0 V, no load		10	2 17	
	ISO7220C, ISO7220M	OF Mhma	\\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\		4		
	ISO7221C, ISO7221M	25 Mbps	$V_I = V_{CC}$ or 0 V, no load		12	22	mA
	ISO7220x	Outenant	\\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\		16	31	mA
	ISO7221x	Quiescent	$V_I = V_{CC}$ or 0 V, no load		17 32		
	ISO7220A, ISO7220B	4 Mb	\\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\		17	32	
I <sub>CC2</sub>	ISO7221A, ISO7221B	1 Mbps	$V_I = V_{CC}$ or 0 V, no load		10	18	
	ISO7220C, ISO7220M	05.845	V = V or 0 V no load		20	34	
	ISO7221C, ISO7221M	25 Mbps	$V_I = V_{CC}$ or 0 V, no load		12	17 32 18 34 22	
1/	Lligh level output voltage		I <sub>OH</sub> = -4 mA, See Figure 1	V <sub>CC</sub> - 0.8	4.6		V
V <sub>OH</sub>	High-level output voltage		I <sub>OH</sub> = -20 μA, See Figure 1	V <sub>CC</sub> - 0.1	5	22 31 17 32 18 34 22 0.4	V
V	Law law law and a set of the sec		I <sub>OL</sub> = 4 mA, See Figure 1		0.2	0.4	V
$V_{OL}$	Low-level output voltage		I <sub>OL</sub> = 20 μA, See Figure 1		0	0.1	V
V <sub>I(HYS)</sub>	Input voltage hysteresis				150		mV
I <sub>IH</sub>	High-level input current		IN from O V to V			10	^
I <sub>IL</sub>	Low-level input current		IN from 0 V to V <sub>CC</sub>	-10			μΑ
Cı	Input capacitance to ground		IN at $V_{CC}$ , $V_{I} = 0.4 \sin (4E6\pi t)$		1		pF
CMTI	Common-mode transient immunity		V <sub>I</sub> = V <sub>CC</sub> or 0 V, See Figure 3	25	50		kV/μs

<sup>(1)</sup> For the 5-V operation,  $V_{CC1}$  or  $V_{CC2}$  is specified from 4.5 V to 5.5 V. For the 3-V operation,  $V_{CC1}$  or  $V_{CC2}$  is specified from 3 V to 3.6 V.

# SWITCHING CHARACTERISTICS: $V_{\text{CC1}}$ and $V_{\text{CC2}}$ at 5-V OPERATION

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t <sub>pLH</sub> , t <sub>pHL</sub>	Propagation delay	ISO722xA		280	405	475	
PWD	Pulse-width distortion $ t_{pHL} - t_{pLH} ^{(1)}$			1	14		
t <sub>pLH</sub> , t <sub>pHL</sub>	Propagation delay	ISO722xB	See Figure 1	42	55	70	
PWD	Pulse-width distortion $ t_{pHL} - t_{pLH} ^{(1)}$				1	3	ns
$t_{pLH}$ , $t_{pHL}$	Propagation delay		See Figure 1	22	32	42	115
PWD	Pulse-width distortion $ t_{pHL} - t_{pLH} ^{(1)}$				1	2	
t <sub>pLH</sub> , t <sub>pHL</sub>	Propagation delay	ISO722xM		6	10	16	
PWD	Pulse-width distortion $ t_{pHL} - t_{pLH} ^{(1)}$				0.5	1	
		ISO722xA				180	
	Part-to-part skew (2)	ISO722xB				17	ns
t <sub>sk(pp)</sub>	Fait-to-pait skew V	ISO722xC				10	
		ISO722xM				3	

<sup>(1)</sup> Also referred to as pulse skew.

<sup>(2)</sup> t<sub>sk(pp)</sub> is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.



**NSTRUMENTS** 

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# SWITCHING CHARACTERISTICS: V<sub>CC1</sub> and V<sub>CC2</sub> at 5-V OPERATION (continued)

over recommended operating conditions (unless otherwise noted)

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
		ISO722xA			3	15	ns
t <sub>sk(o)</sub>	Channel-to-channel output skew (3)	ISO722xB			0.6	3	
		ISO722xC/M			0.2	3 15	
t <sub>r</sub>	Output signal rise time		See Figure 4		1		
t <sub>f</sub>	Output signal fall time		See Figure 1		1		ns
t <sub>fs</sub>	Failsafe output delay time from input power loss		See Figure 2		3		μs
t <sub>jit(pp)</sub>	Peak-to-peak eye-pattern jitter	ISO722xM	150 Mbps PRBS NRZ data, 5-bit max same polarity input, both channels, See Figure 4, Figure 17	1			ns
J(PP)			150 Mbps unrestricted bit run length data input, both channels, See Figure 4		2		

<sup>(3)</sup>  $t_{sk(o)}$  is the skew between specified outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical specified loads.

# ELECTRICAL CHARACTERISTICS: V<sub>CC1</sub> at 5 V, V<sub>CC2</sub> at 3.3 V<sup>(1)</sup> OPERATION

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY	CURRENT						
	ISO7220x	Quiescent	$V_I = V_{CC}$ or 0 V, no load		1	2	
	ISO7221x	Quiescent	$V_1 = V_{CC}$ or $V_1$ no load		8.5	17	
	ISO7220A, ISO7220B	1 Mbps	$V_I = V_{CC}$ or 0 V, no load		2	3	
I <sub>CC1</sub>	ISO7221A, ISO7221B	1 Mbps	$V_1 = V_{CC}$ or $V_1$ no load		10	18	
	ISO7220C, ISO7220M	05 Mb	)/		4	9	mA
	ISO7221C, ISO7221M	25 Mbps	V <sub>I</sub> = V <sub>CC</sub> or 0 V, no load		12	22	
	ISO7220x	Quiescent	\/ \/ or 0\/ no load		8	18	MA
	ISO7221x	Quiescent	$V_I = V_{CC}$ or 0 V, no load		4.3	9.5	
	ISO7220A, ISO7220B	4 14	)/		9	9 19 5 11 10 20	
I <sub>CC2</sub>	ISO7221A, ISO7221B	1 Mbps	$V_I = V_{CC}$ or 0 V, no load		5		
	ISO7220C, ISO7220M	05 Mb	)/		10		
	ISO7221C, ISO7221M	25 Mbps	$V_I = V_{CC}$ or 0 V, no load		6	12	
		ISO7220x	I <sub>OH</sub> = -4 mA, See Figure 1	V <sub>CC</sub> - 0.4			
V <sub>OH</sub>	High-level output voltage	ISO7221x (5-V side)		V <sub>CC</sub> - 0.8			V
			$I_{OH} = -20 \mu A$ , See Figure 1	V <sub>CC</sub> - 0.1			
\/	Low-level output voltage		I <sub>OL</sub> = 4 mA, See Figure 1			0.4	V
V <sub>OL</sub>	Low-level output voltage		I <sub>OL</sub> = 20 μA, See Figure 1			0.1	V
$V_{I(HYS)}$	Input voltage hysteresis				150		mV
I <sub>IH</sub>	High-level input current		IN from 0 V to V <sub>CC</sub>			10	
I <sub>IL</sub>	Low-level input current		IIA HOILI O A IO ACC	-10			μΑ
Cı	Input capacitance to ground		IN at $V_{CC}$ , $V_{I} = 0.4 \sin (4E6\pi t)$		1		pF
CMTI	Common-mode transient immunity		V <sub>I</sub> = V <sub>CC</sub> or 0 V, See Figure 3	15	40		kV/μs

<sup>(1)</sup> For the 5-V operation,  $V_{CC1}$  or  $V_{CC2}$  is specified from 4.5 V to 5.5 V. For the 3-V operation,  $V_{CC1}$  or  $V_{CC2}$  is specified from 3 V to 3.6 V.



#### SWITCHING CHARACTERISTICS: V<sub>CC1</sub> at 5 V, V<sub>CC2</sub> at 3.3 V OPERATION

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$t_{pLH}$ , $t_{pHL}$	Propagation delay	ISO722xA		285	410	480	
PWD	Pulse-width distortion $ t_{pHL} - t_{pLH} ^{(1)}$				1	14	
$t_{pLH}$ , $t_{pHL}$	Propagation delay	ISO722xB		45	58	75	
PWD	Pulse-width distortion  t <sub>pHL</sub> - t <sub>pLH</sub>   <sup>(1)</sup>		See Figure 1		1	3	ns
$t_{pLH}$ , $t_{pHL}$	Propagation delay	ISO722xC	- See rigule r	25	36	48	115
PWD	Pulse-width distortion $ t_{pHL} - t_{pLH} ^{(1)}$				1	2	
$t_{pLH}$ , $t_{pHL}$	Propagation delay	ISO722xM		7	12	20	
PWD	Pulse-width distortion $ t_{pHL} - t_{pLH} ^{(1)}$				0.5	1	
		ISO722xA				180	
	Part-to-part skew (2)	ISO722xB			17		
t <sub>sk(pp)</sub>	Part-to-part skew (=/	ISO722xC				10	
		ISO722xM				5	ns
		ISO722xA			3	15	
t <sub>sk(o)</sub>	Channel-to-channel output skew (3)	ISO722xB			0.6	3	
		ISO722xC/M			0.2	1	
t <sub>r</sub>	Output signal rise time		2 = .		2		
t <sub>f</sub>	Output signal fall time		See Figure 1		2		ns
t <sub>fs</sub>	Failsafe output delay time from input power loss		See Figure 2		3		μs
t <sub>jit(pp)</sub>	Peak-to-peak eye-pattern jitter	ISO722xM	150 Mbps PRBS NRZ data, 5-bit max same polarity input, both channels, See Figure 4, Figure 17		1		ns
1(bb)	. , ,		150 Mbps unrestricted bit run length data input, both channels, See Figure 4		2		

<sup>(1)</sup> Also referred to as pulse skew.

 $t_{\text{sk(pp)}}$  is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.  $t_{sk(o)}$  is the skew between specified outputs of a single device with all driving inputs connected together and the outputs switching in the

same direction while driving identical specified loads.



**INSTRUMENTS** 

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# ELECTRICAL CHARACTERISTICS: V<sub>CC1</sub> at 3.3 V, V<sub>CC2</sub> at 5 V<sup>(1)</sup> OPERATION

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPL	Y CURRENT						
	ISO7220x	Quiescent	V V 27 0 V 72 lood		0.6	1	
	ISO7221x	Quiescent	$V_I = V_{CC}$ or 0 V, no load		4.3	9.5	
	ISO7220A, ISO7220B	1 Mbps	$V_1 = V_{CC}$ or 0 V, no load		1	1	
I <sub>CC1</sub>	ISO7221A, ISO7221B	1 Mbps	V <sub>I</sub> = V <sub>CC</sub> or 0 V, no load		5		
	ISO7220C, ISO7220M	25 Mhna	\\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\		2		mA
	ISO7221C, ISO7221M	25 Mbps	$V_I = V_{CC}$ or 0 V, no load		6	12	
	ISO7220x	Quincont	$V_{L} = V_{CC}$ or 0 V, no load		16	31	ША
	ISO7221x	Quiescent	V <sub>I</sub> = V <sub>CC</sub> or 0 V, no load		8.5	17	
	ISO7220A, ISO7220B	1 Mbps	// // or 0 // no load		18	18 34	
I <sub>CC2</sub>	ISO7221A, ISO7221B	1 Mbps	$V_I = V_{CC}$ or 0 V, no load		10		
	ISO7220C, ISO7220M	25 Mbps	\\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\		20		
	ISO7221C, ISO7221M	25 Mbps	$V_I = V_{CC}$ or 0 V, no load		12	22	
		ISO7220x		V <sub>CC</sub> - 0.8			
$V_{OH}$	High-level output voltage	ISO7221x (3.3-V side)	I <sub>OH</sub> = -4 mA, See Figure 1	V <sub>CC</sub> - 0.4			
			$I_{OH} = -20 \mu A$ , See Figure 1	V <sub>CC</sub> - 0.1			V
	Low lovel output voltage		IOL = 4 mA, See Figure 1			0.4	
$V_{OL}$	Low-level output voltage		IOL = 20 μA, See Figure 1		0	0.1	
V <sub>I(HYS)</sub>	Input threshold voltage hysteresis				150		mV
I <sub>IH</sub>	High-level input current		IN from 0 V or V <sub>CC</sub>			10	
$I_{\text{IL}}$	Low-level input current		IN HOM O V OF VCC	-10			μΑ
Cı	Input capacitance to ground		IN at $V_{CC}$ , $V_I = 0.4 \sin (4E6\pi t)$		1		pF
CMTI	Common-mode transient immunity		V <sub>I</sub> = V <sub>CC</sub> or 0 V, See Figure 3	15	40		kV/μs

<sup>(1)</sup> For the 5-V operation,  $V_{CC1}$  or  $V_{CC2}$  is specified from 4.5 V to 5.5 V. For the 3-V operation,  $V_{CC1}$  or  $V_{CC2}$  is specified from 3 V to 3.6 V.



#### SWITCHING CHARACTERISTICS: V<sub>CC1</sub> at 3.3 V, V<sub>CC2</sub> at 5 V OPERTAION

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t <sub>pLH</sub> , t <sub>pHL</sub>	Propagation delay	ISO722xA		285	395	480	
PWD	Pulse-width distortion $ t_{pHL} - t_{pLH} ^{(1)}$				1	18	
$t_{pLH}$ , $t_{pHL}$	Propagation delay	ISO722xB		45	58	75	
PWD	Pulse-width distortion $ t_{pHL} - t_{pLH} ^{(1)}$		See Figure 1		1	4	
t <sub>pLH</sub> , t <sub>pHL</sub>	Propagation delay	ISO722xC	See rigule i	25	36	48	
PWD	Pulse-width distortion $ t_{pHL} - t_{pLH} ^{(1)}$				1	3	
t <sub>pLH</sub> , t <sub>pHL</sub>	Propagation delay	ISO722xM		7	12	21	
PWD	Pulse-width distortion $ t_{pHL} - t_{pLH} ^{(1)}$				0.5	1	ns
		ISO722xA				190	
	Part-to-part skew (2)	ISO722xB				17	
t <sub>sk(pp)</sub>	ran-to-part skew ·	ISO722xC				10	
		ISO722xM				5	
		ISO722xA			3	15	
$t_{sk(o)}$	Channel-to-channel output skew (3)	ISO722xB			0.6	3	
		ISO7220C/M			0.2	1	
t <sub>r</sub>	Output signal rise time	·	Con Figure 4		1		
t <sub>f</sub>	Output signal fall time		See Figure 1		1		
t <sub>fs</sub>	Failsafe output delay time from input po	wer loss	See Figure 2		3		μs
t <sub>jit(pp)</sub>	Peak-to-peak eye-pattern jitter	ISO722xM	150 Mbps PRBS NRZ data, 5-bit max same polarity input, both channels, See Figure 4, Figure 17		1		ns
1.(56)	,	IJOT ZZAIVI	150 Mbps unrestricted bit run length data input, both channels, See Figure 4		2		115

<sup>(1)</sup> Also referred to as pulse skew.

 $t_{\text{sk(pp)}}$  is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.  $t_{sk(o)}$  is the skew between specified outputs of a single device with all driving inputs connected together and the outputs switching in the

same direction while driving identical specified loads.



**INSTRUMENTS** 

SLLS755H-JULY 2006-REVISED MAY 2008

# ELECTRICAL CHARACTERISTICS: V<sub>CC1</sub> and V<sub>CC2</sub> at 3.3 V<sup>(1)</sup> OPERATION

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SUPPLY	CURRENT			1		',	
	ISO7220x	0	V V 0 V l d		0.6	1	
	ISO7221x	Quiescent	$V_I = V_{CC}$ or 0 V, no load		4.3	9.5	
	ISO7220A, ISO7220B	4 14 1	V V 0 V l		1	2	
I <sub>CC1</sub>	ISO7221A, ISO7221B	1 Mbps	$V_I = V_{CC}$ or 0 V, no load		5	9.5 2 3 11 2 4 5 12 6 18 9.5 1 19 6 11 20 6 12	
	ISO7220C, ISO7220M	05 Mb	V V 0 V l		2	4	
	ISO7221C, ISO7221M	25 Mbps	$V_I = V_{CC}$ or 0 V, no load		6	12	A
	ISO7220x	0	V V 0 V l		8	18	mA
	ISO7221x	Quiescent	$V_I = V_{CC}$ or 0 V, no load		4.3	9.5	
	ISO7220A, ISO7220B	4 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	V V 0 V l d		9	19	
I <sub>CC2</sub>	ISO7221A, ISO7221B	1 Mbps	$V_I = V_{CC}$ or 0 V, no load		5	11	
	ISO7220C, ISO7220M	05 Mb	V V 0 V ll		10	20	
	ISO7221C, ISO7221M	25 Mbps	$V_I = V_{CC}$ or 0 V, no load		6	18 9.5 19 11 20 12	
	High level output voltege		I <sub>OH</sub> = -4 mA, See Figure 1	V <sub>CC</sub> - 0.4	3		
V <sub>OH</sub>	High-level output voltage		$I_{OH} = -20 \mu A$ , See Figure 1	V <sub>CC</sub> - 0.1	3.3		V
	Low level cutout veltage		I <sub>OL</sub> = 4 mA, See Figure 1		0.2	0.4	V
V <sub>OL</sub>	Low-level output voltage		I <sub>OL</sub> = 20 μA, See Figure 1		0	0.1	
V <sub>I(HYS)</sub>	Input voltage hysteresis				150		mV
I <sub>IH</sub>	High-level input current		IN form O.V. on V.			10	^
I <sub>IL</sub>	Low-level input current		IN from 0 V or V <sub>CC</sub>	-10			μΑ
Cı	Input capacitance to ground		IN at $V_{CC}$ , $V_{I} = 0.4 \sin (4E6\pi t)$		1		pF
CMTI	Common-mode transient immunity	,	V <sub>I</sub> = V <sub>CC</sub> or 0 V, See Figure 3	15	40		kV/μs

<sup>(1)</sup> For the 5-V operation,  $V_{CC1}$  or  $V_{CC2}$  is specified from 4.5 V to 5.5 V. For the 3-V operation,  $V_{CC1}$  or  $V_{CC2}$  is specified from 3 V to 3.6 V.



#### **SWITCHING CHARACTERISTICS**

V<sub>CC1</sub> and V<sub>CC2</sub> at 3.3 V operation, over recommended operating conditions (unless otherwise noted)

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
t <sub>pLH</sub> , t <sub>pHL</sub>	Propagation delay	ISO722xA		290	400	485	
PWD	Pulse-width distortion $ t_{pHL} - t_{pLH} ^{(1)}$				1	18	
t <sub>pLH</sub> , t <sub>pHL</sub>	Propagation delay	ISO722xB		46	62	78	
PWD	Pulse-width distortion $ t_{pHL} - t_{pLH} ^{(1)}$		See Figure 1		1	4	
t <sub>pLH</sub> , t <sub>pHL</sub>	Propagation delay	ISO722xC	- See Figure 1	26	40	52	
PWD	Pulse-width distortion  t <sub>pHL</sub> - t <sub>pLH</sub>   <sup>(1)</sup>				1	3	
t <sub>pLH</sub> , t <sub>pHL</sub>	Propagation delay	ISO722xM		8	16	25	
PWD	Pulse-width distortion  t <sub>pHL</sub> - t <sub>pLH</sub>   <sup>(1)</sup>				0.5	1	ns
		ISO722xA				190	
	Part-to-part skew <sup>(2)</sup>	ISO722xB				17	
t <sub>sk(pp)</sub>	Pan-to-pan skew -/	ISO722xC				10	
		ISO722xM				5	
		ISO722xA			3	15	
t <sub>sk(o)</sub>	Channel-to-channel output skew (3)	ISO722xB			0.6	3	
		ISO722xC/M			0.2	1	
t <sub>r</sub>	Output signal rise time		0 5		2		
t <sub>f</sub>	Output signal fall time		See Figure 1		2		
t <sub>fs</sub>	Failsafe output delay time from input power loss	See Figure 2		3		μs	
t <sub>jit(pp)</sub>	Peak-to-peak eye-pattern jitter	ISO722xM	150 Mbps PRBS NRZ data, 5-bit max same polarity input, both channels, See Figure 4, Figure 17		1		ns
7.417	геак-ю-реак еуе-рашет julei		150 Mbps unrestricted bit run length data input, both channels, See Figure 4		2		

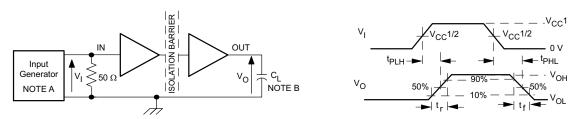
<sup>(1)</sup> Also referred to as pulse skew.

 $t_{\text{sk(pp)}}$  is the magnitude of the difference in propagation delay times between any specified terminals of two devices when both devices

operate with the same supply voltages, at the same temperature, and have identical packages and test circuits.  $t_{sk(o)}$  is the skew between specified outputs of a single device with all driving inputs connected together and the outputs switching in the same direction while driving identical specified loads.

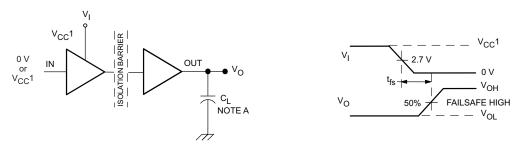


#### PARAMETER MEASUREMENT INFORMATION



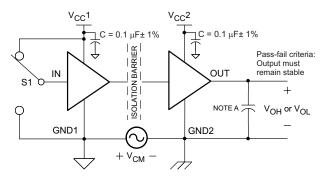
- A. The input pulse is supplied by a generator having the following characteristics: PRR  $\leq$  50 kHz, 50% duty cycle,  $t_r \leq$  3 ns,  $t_f \leq$  3 n
- B.  $C_L = 15$  pF and includes instrumentation and fixture capacitance within  $\pm 20\%$ .

Figure 1. Switching Characteristic Test Circuit and Voltage Waveforms



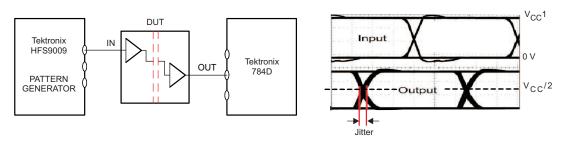
A.  $C_L = 15 \text{ pF}$  and includes instrumentation and fixture capacitance within  $\pm 20\%$ .

Figure 2. Failsafe Delay Time Test Circuit and Voltage Waveforms



A.  $C_L = 15$  pF and includes instrumentation and fixture capacitance within  $\pm 20\%$ .

Figure 3. Common-Mode Transient Immunity Test Circuit



NOTE: PRBS bit pattern run length is  $2^{16} - 1$ . Transition time is 800 ps.

Figure 4. Peak-to-Peak Eye-Pattern Jitter Test Circuit and Voltage Waveform



#### **DEVICE INFORMATION**

#### IEC PACKAGE CHARACTERISTICS

	PARAMETER	TEST CONDITIONS		MIN	TYP	MAX	UNIT
L(I01)	Minimum air gap (Clearance)	Shortest terminal-to-terminal distance through air		4.8			mm
L(102)	Minimum external tracking (Creepage)	Shortest terminal-to-terminal distance across the package surface	SOIC-8	4.3			mm
CTI	Tracking resistance (Comparative Tracking Index)	DIN IEC 60112 / VDE 0303 Part 1	≥175			V	
	Minimum Internal Gap (Internal Clearance)	Distance through the insulation	0.008			mm	
R <sub>IO</sub>	Isolation resistance	Input to output, $V_{IO} = 500$ V, all pins on each side barrier tied together creating a two-terminal device $T_A < 100^{\circ}\text{C}$			>10 <sup>12</sup>		Ω
		Input to output, V <sub>IO</sub> = 500 V, 100°C ≤ T <sub>A</sub> ≤ max	Input to output, V <sub>IO</sub> = 500 V, 100°C ≤ T <sub>A</sub> ≤ max				
C <sub>IO</sub>	Barrier capacitance Input to output	$V_{I} = 0.4 \sin (4E6\pi t)$ 1					pF
CI	Input capacitance to ground	$V_{I} = 0.4 \sin (4E6\pi t)$		1		pF	

**NOTE:** Creepage and clearance requirements should be applied according to the specific equipment isolation standards of an application. Care should be taken to maintain the creepage and clearance distance of a board design to ensure that the mounting pads of the isolator on the printed circuit board do not reduce this distance.

Creepage and clearance on a printed circuit board become equal according to the measurement techniques shown in the *Isolation Glossary*. Techniques such as inserting grooves and/or ribs on a printed circuit board are used to help increase these specifications.

#### **IEC 60664-1 RATINGS TABLE**

PARAMETER	TEST CONDITIONS	SPECIFICATION
Basic isolation group	Material group	Illa
	Rated mains voltage ≤150 VRMS	I-IV
Installation classification	Rated mains voltage ≤300 VRMS	I-III
	Rated mains voltage ≤400 VRMS	I-II

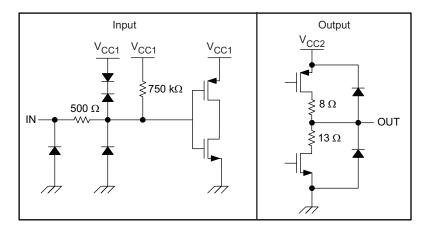
#### IEC 60747-5-2 INSULATION CHARACTERISTICS(1)

	PARAMETER	TEST CONDITIONS	SPECIFICATION	UNIT
$V_{IORM}$	Maximum working insulation voltage		560	
V <sub>PR</sub>	Input to output test voltage	Method b1, V <sub>PR</sub> = V <sub>IORM</sub> × 1.875, 100% Production test with t = 1 s, Partial discharge <5 pC	1050	V
$V_{IOTM}$	Transient overvoltage	t = 60 s	4000	
R <sub>S</sub>	Insulation resistance	$V_{IO} = 500 \text{ V at } T_{S}$	>10 <sup>9</sup>	Ω
	Pollution degree		2	

(1) Climatic Classification 40/125/21



#### **DEVICE I/O SCHEMATICS**



#### **IEC SAFETY LIMITING VALUES**

Safety limiting intends to prevent potential damage to the isolation barrier upon failure of input or output circuitry. A failure of the IO can allow low resistance to ground or the supply and, without current limiting, dissipate sufficient power to overheat the die and damage the isolation barrier potentially leading to secondary system failures.

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
	Safety input, output, or	SOIC-8	$\theta_{JA} = 212^{\circ}\text{C/W}, \ V_{I} = 5.5 \ \text{V}, \ T_{J} = 170^{\circ}\text{C}, \ T_{A} = 25^{\circ}\text{C}$			124	mΛ
IS	supply current	3010-6	$\theta_{JA} = 212^{\circ}\text{C/W}, \ V_{I} = 3.6 \ \text{V}, \ T_{J} = 170^{\circ}\text{C}, \ T_{A} = 25^{\circ}\text{C}$			190	mA
T <sub>S</sub>	Maximum case temperature	SOIC-8				150	°C

The safety-limiting constraint is the absolute maximum junction temperature specified in the absolute maximum ratings table. The power dissipation and junction-to-air thermal impedance of the device installed in the application hardware determines the junction temperature. The assumed junction-to-air thermal resistance in the Thermal Characteristics table is that of a device installed in the JESD51-3, Low Effective Thermal Conductivity Test Board for Leaded Surface Mount Packages and is conservative. The power is the recommended maximum input voltage times the current. The junction temperature is then the ambient temperature plus the power times the junction-to-air thermal resistance.



#### SOIC-8 PACKAGE THERMAL CHARACTERISTICS

over recommended operating conditions (unless otherwise noted)

	PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
0	Junction-to-air		Low-K Thermal Resistance <sup>(1)</sup>		212		
$\theta_{JA}$			High-K Thermal Resistance		122		°C/W
$\theta_{JB}$	Junction-to-Board Thermal	Resistance			37		°C/VV
$\theta_{\text{JC}}$	Junction-to-Case Thermal Resistance				69.1		
P <sub>D</sub>	Device Power Dissipation	ISO722xM	$V_{CC1} = V_{CC2} = 5.5 \text{ V}, T_J = 150^{\circ}\text{C}, C_L = 15 \text{ pF},$ Input a 150 Mbps 50% duty cycle square wave			390	mW

(1) Tested in accordance with the Low-K or High-K thermal metric definitions of EIA/JESD51-3 for leaded surface mount packages.

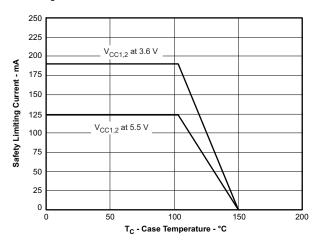


Figure 5. SOIC-8  $\theta_{\text{JC}}$  THERMAL DERATING CURVE per IEC 60747-5-2

#### **DEVICE FUNCTION TABLE**

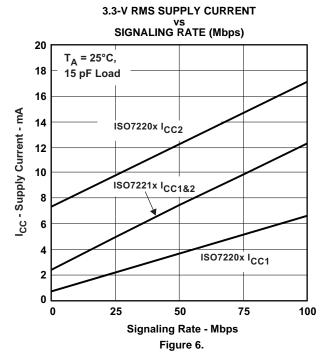
Table 1. ISO7220x or ISO7221x<sup>(1)</sup>

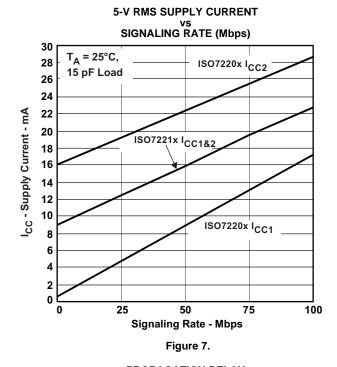
INPUT SIDE V <sub>CC</sub>	OUTPUT SIDE V <sub>CC</sub>	INPUT IN	OUTPUT OUT
		Н	Н
PU	PU	L	L
		Open	Н
PD	PU	X	Н

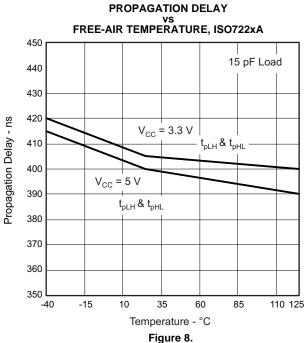
<sup>(1)</sup> PU = Powered Up(Vcc ≥ 3.0V); PD = Powered Down (Vcc ≤ 2.5V); X = Irrelevant; H = High Level; L = Low Level

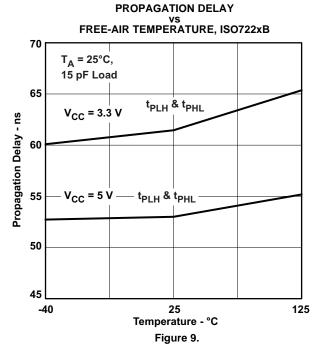


#### TYPICAL CHARACTERISTIC CURVES







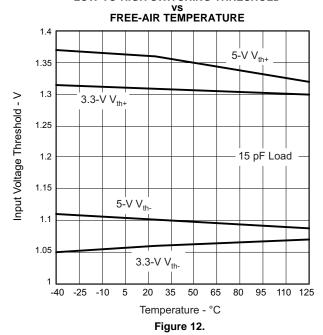




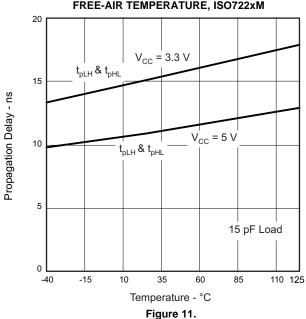
#### TYPICAL CHARACTERISTIC CURVES (continued)

# PROPAGATION DELAY vs FREE-AIR TEMPERATURE, ISO722xC 30 $V_{CC} = 3.3 \text{ V}$ 25 t<sub>DLH</sub> & t<sub>PHL</sub> Propagation Delay - ns 20 $V_{CC} = 5 V$ 15 10 15 pF Load -15 110 125 Temperature - °C Figure 10.

# ISO722xA, ISO722xB AND ISO722xC INPUT VOLTAGE LOW-TO-HIGH SWITCHING THRESHOLD



#### PROPAGATION DELAY vs FREE-AIR TEMPERATURE, ISO722xM



# ISO722xM INPUT VOLTAGE HIGH-TO-LOW vs

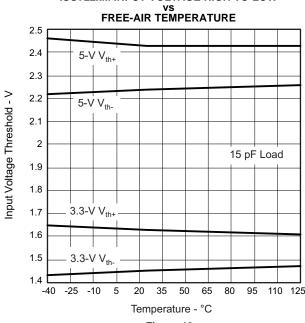


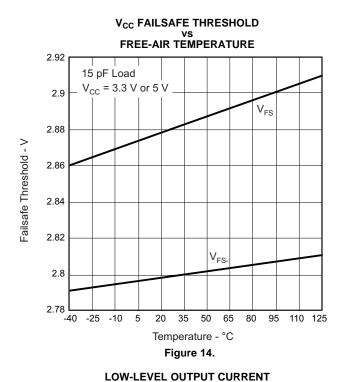
Figure 13.

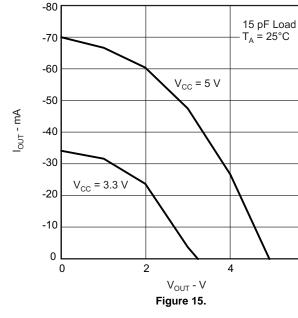
HIGH-LEVEL OUTPUT CURRENT

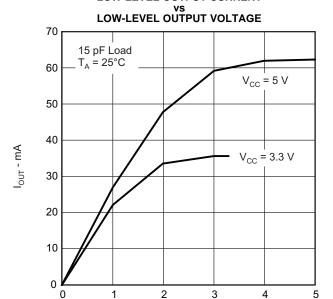
vs HIGH-LEVEL OUTPUT VOLTAGE



#### **TYPICAL CHARACTERISTIC CURVES (continued)**

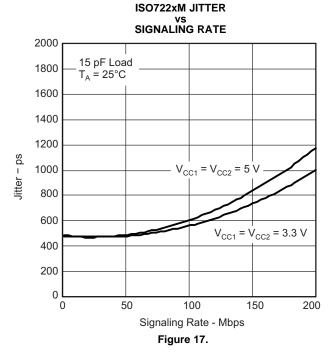






V<sub>OUT</sub> - V

Figure 16.



6



#### **APPLICATION INFORMATION**

#### **Typical Applications**

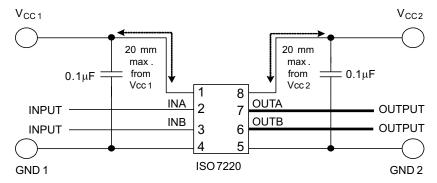


Figure 18. Typical ISO7220 Application Circuit

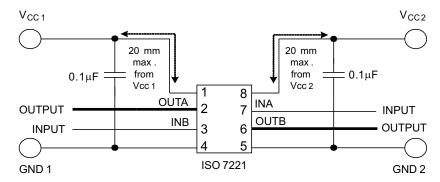


Figure 19. Typical ISO7221 Application Circuit

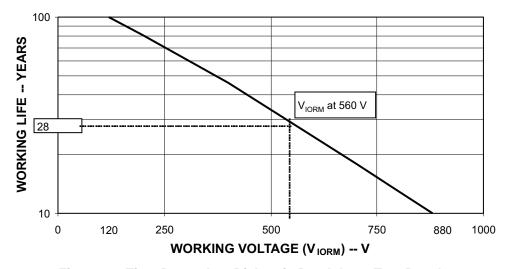
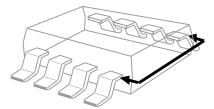


Figure 20. Time Dependent Dielectric Breakdown Test Results

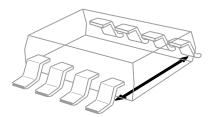


#### **ISOLATION GLOSSARY**

**Creepage Distance** — The shortest path between two conductive input to output leads measured along the surface of the insulation. The shortest distance path is found around the end of the package body.



**Clearance** — The shortest distance between two conductive input to output leads measured through air (line of sight).



**Input-to Output Barrier Capacitance** — The total capacitance between all input terminals connected together, and all output terminals connected together.

**Input-to Output Barrier Resistance** — The total resistance between all input terminals connected together, and all output terminals connected together.

**Primary Circuit** — An internal circuit directly connected to an external supply mains or other equivalent source which supplies the primary circuit electric power.

**Secondary Circuit** — A circuit with no direct connection to primary power, and derives its power from a separate isolated source.

Comparative Tracking Index (CTI) — CTI is an index used for electrical insulating materials which is defined as the numerical value of the voltage which causes failure by tracking during standard testing. Tracking is the process that produces a partially conducting path of localized deterioration on or through the surface of an insulating material as a result of the action of electric discharges on or close to an insulation surface -- the higher CTI value of the insulating material, the smaller the minimum creepage distance.

Generally, insulation breakdown occurs either through the material, over its surface, or both. Surface failure may arise from flashover or from the progressive degradation of the insulation surface by small localized sparks. Such sparks are the result of the breaking of a surface film of conducting contaminant on the insulation. The resulting break in the leakage current produces an overvoltage at the site of the discontinuity, and an electric spark is generated. These sparks often cause carbonization on insulation material and lead to a carbon track between points of different potential. This process is known as *tracking*.

# ISO7220A, ISO7220B, ISO7220C, ISO7220M ISO7221A, ISO7221B, ISO7221C, ISO7221M

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INSTRUMENTS

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#### Insulation:

Operational insulation — Insulation needed for the correct operation of the equipment.

Basic insulation — Insulation to provide basic protection against electric shock.

Supplementary insulation — Independent insulation applied in addition to basic insulation in order to ensure protection against electric shock in the event of a failure of the basic insulation.

Double insulation — Insulation comprising both basic and supplementary insulation.

Reinforced insulation — A single insulation system which provides a degree of protection against electric shock equivalent to double insulation.

#### **Pollution Degree:**

Pollution Degree 1 — No pollution, or only dry, nonconductive pollution occurs. The pollution has no influence.

Pollution Degree 2 — Normally, only nonconductive pollution occurs. However, a temporary conductivity caused by condensation must be expected.

Pollution Degree 3 — Conductive pollution occurs or dry nonconductive pollution occurs which becomes conductive due to condensation which is to be expected.

Pollution Degree 4 - Continuous conductivity occurs due to conductive dust, rain, or other wet conditions.

#### **Installation Category:**

Overvoltage Category — This section is directed at insulation co-ordination by identifying the transient overvoltages which may occur, and by assigning 4 different levels as indicated in IEC 60664.

- I: Signal Level Special equipment or parts of equipment.
- II: Local Level Portable equipment etc.
- III: Distribution Level Fixed installation
- IV: Primary Supply Level Overhead lines, cable systems

Each category should be subject to smaller transients than the category above.



#### **PACKAGING INFORMATION**

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
ISO7220AD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
ISO7220ADG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
ISO7220ADR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
ISO7220ADRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
ISO7220BD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
ISO7220BDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
ISO7220BDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
ISO7220BDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
ISO7220CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
ISO7220CDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
ISO7220CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
ISO7220CDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
ISO7220MD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
ISO7220MDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
ISO7220MDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
ISO7220MDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
ISO7221AD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
ISO7221ADG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
ISO7221ADR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
ISO7221ADRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
ISO7221BD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
ISO7221BDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
ISO7221BDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
ISO7221BDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
ISO7221CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM



#### PACKAGE OPTION ADDENDUM

11-Jul-2008

Orderable Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp <sup>(3)</sup>
ISO7221CDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
ISO7221CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
ISO7221CDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
ISO7221MD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
ISO7221MDG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
ISO7221MDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
ISO7221MDRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

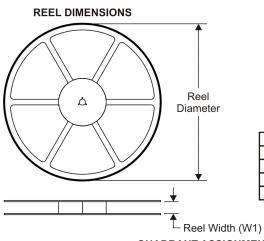
(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

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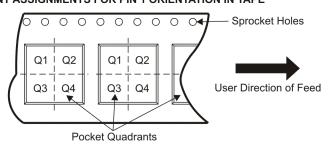
#### TAPE AND REEL INFORMATION



# TAPE DIMENSIONS + K0 - P1 - B0 W Cavity - A0 -

	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	Package Type	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
ISO7220ADR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
ISO7220BDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
ISO7220CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
ISO7220MDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
ISO7221ADR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
ISO7221BDR	SOIC	D	8	2500	330.0	13.0	6.4	5.2	2.1	8.0	12.0	Q1
ISO7221CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
ISO7221MDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1





\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
ISO7220ADR	SOIC	D	8	2500	358.0	335.0	35.0
ISO7220BDR	SOIC	D	8	2500	358.0	335.0	35.0
ISO7220CDR	SOIC	D	8	2500	358.0	335.0	35.0
ISO7220MDR	SOIC	D	8	2500	358.0	335.0	35.0
ISO7221ADR	SOIC	D	8	2500	358.0	335.0	35.0
ISO7221BDR	SOIC	D	8	2500	358.0	335.0	35.0
ISO7221CDR	SOIC	D	8	2500	358.0	335.0	35.0
ISO7221MDR	SOIC	D	8	2500	358.0	335.0	35.0

# D (R-PDSO-G8)

#### PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 (0,15) per end.
- Body width does not include interlead flash. Interlead flash shall not exceed .017 (0,43) per side.
- E. Reference JEDEC MS-012 variation AA.



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